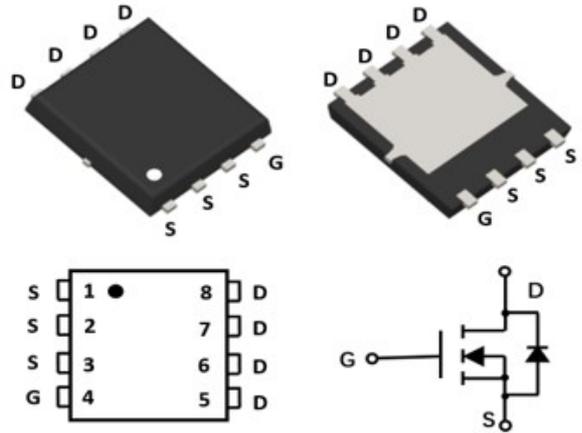


## 79N100

### N-CHANNEL MOSFET

PDFN 5X6



#### FEATURES

- Low on-resistance
- Fast switching speed
- Easily designed drive circuits
- Easy to parallel

#### MECHANICAL DATA

- Case: PDFN5x6
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	$V_{DS}$	100	V
Gate-source voltage	$V_{GS}$	$\pm 20\text{V}$	V
Continuous drain current	$I_D$	79	A
Power dissipation	$P_D$	100	W
Thermal resistance from Junction to ambient	$R_{\theta JA}$	45	$^\circ\text{C/W}$
Junction and Storage temperature	$T_J, T_{STG}$	-55 ~ +150	$^\circ\text{C}$

#### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
<b>Off Characteristics</b>						
Drain-Source breakdown voltage	$V_{(BR)DSS}$	100			V	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$
Zero gate voltage drain current	$I_{DSS}$			1	$\mu\text{A}$	$V_{DS}=80\text{V}, V_{GS}=0\text{V}$
Gate-body leakage current	$I_{GSS}$			$\pm 100$	nA	$V_{DS}=0\text{V}, V_{GS}=\pm 20\text{V}$
Gate-threshold voltage (note 1)	$V_{GS(th)}$	1.2	1.8	2.5		$V_{DS}=20\text{V}, I_D=250\mu\text{A}$
Drain-source on-resistance (note 1)	$R_{DS(on)}$		6.8	8	m $\Omega$	$V_{GS}=10\text{V}, I_D=30\text{A}$
			10.5	12.5	m $\Omega$	$V_{GS}=4.5\text{V}, I_D=15\text{A}$
<b>Dynamic Characteristics</b>						
Input capacitance	$C_{iss}$		3650		pF	$V_{DS}=50\text{V}, V_{GS}=0\text{V}, f=1\text{MHz}$
Output capacitance	$C_{oss}$		320		pF	
Reverse transfer capacitance	$C_{rss}$		22		pF	
<b>Switching Characteristics</b>						
Turn-on delay time	$t_{d(on)}$		16		nS	$V_{DD}=50\text{V}, I_D=40\text{A}$ $R_g=2\Omega$
Turn-on rise time	$t_r$		11		nS	
Turn-off delay time	$t_{d(off)}$		35		nS	
Turn-off fall time	$t_f$		9		nS	

Note:1. Pulse test ; Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$  .

## Typical Characteristics

Figure 1. Output Characteristics

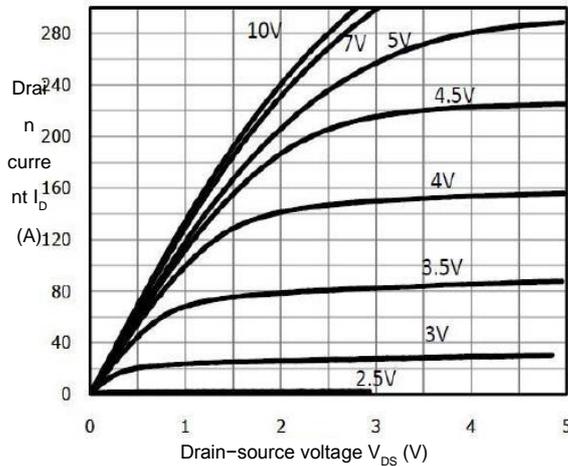


Figure 2. Transfer Characteristics

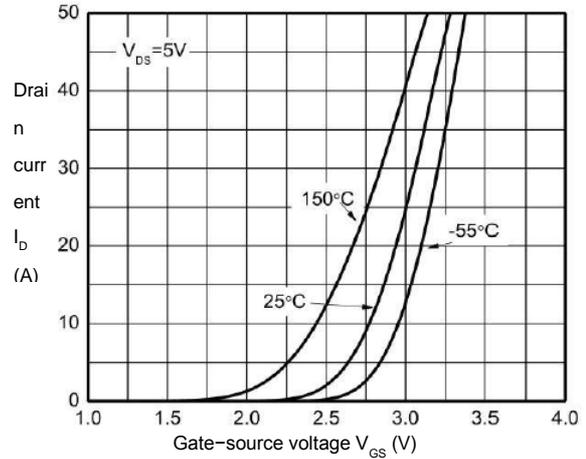


Figure 3. On-Resistance vs. Drain Current

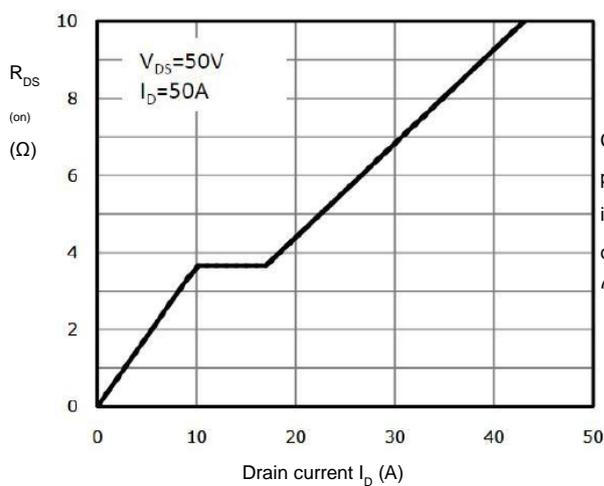


Figure 4. Capacitance Characteristics

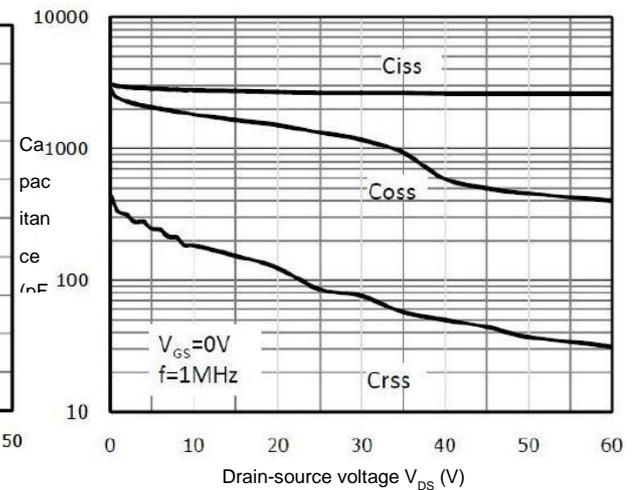


Figure 5. Gate Charge Characteristics

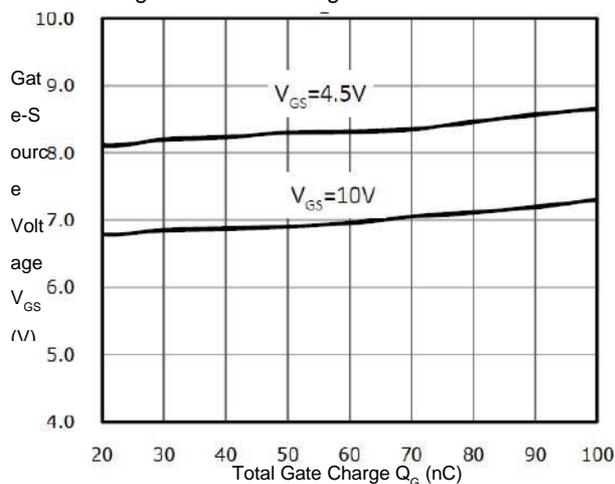
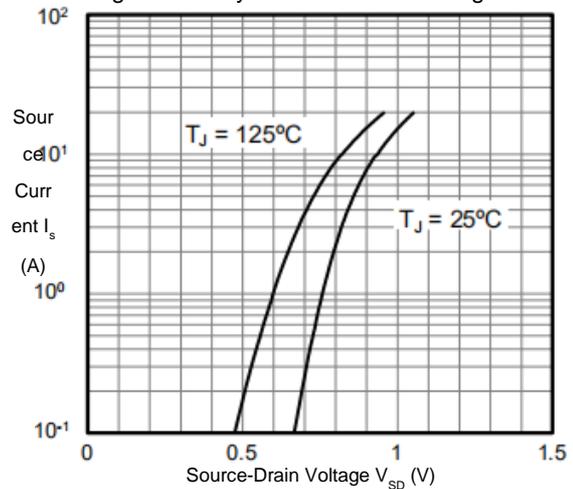


Figure 6. Body Diode Forward Voltage



## Typical Characteristics

Figure 7. Breakdown Voltage vs. Temperature

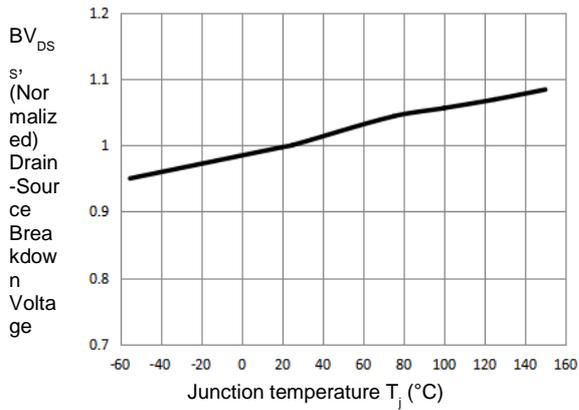


Figure 8. On-Resistance vs. Temperature

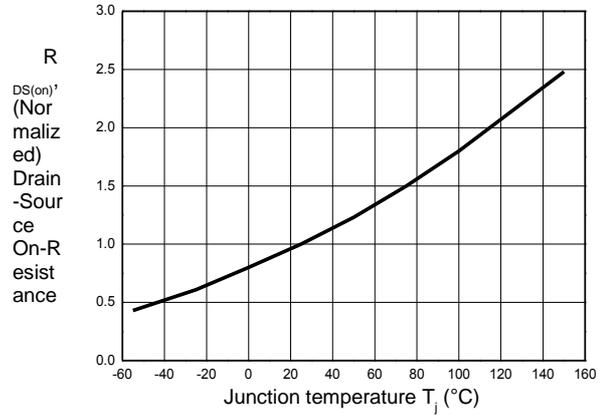


Figure 9. Transient Thermal Impedance

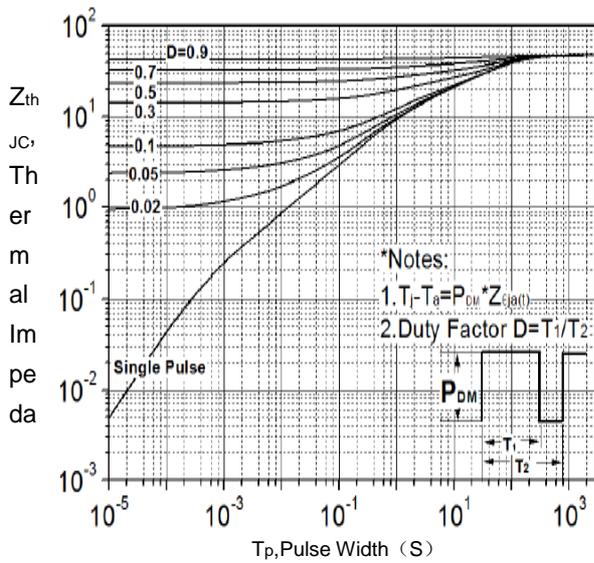
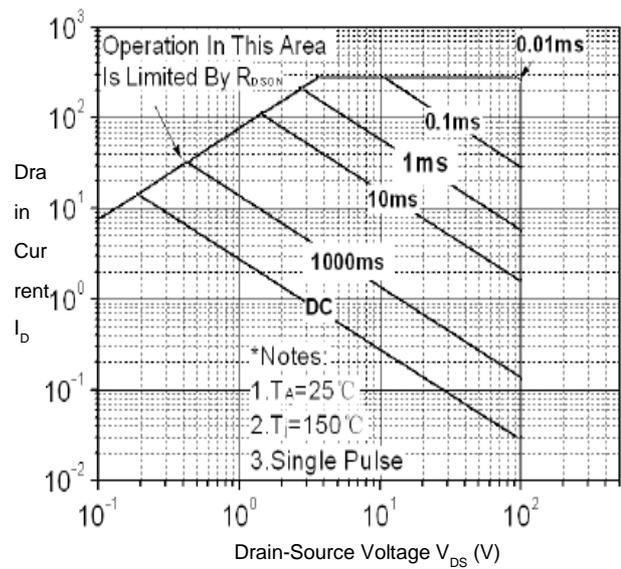
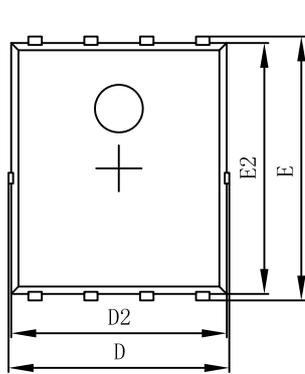


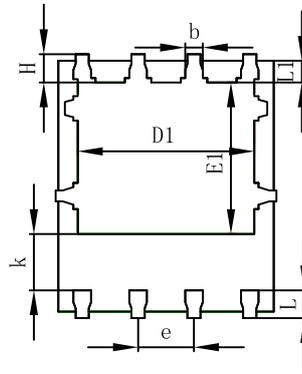
Figure 10. Maximum Safe Operating Area



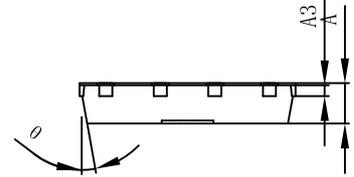
## PDFN5X6 Package information



Top View



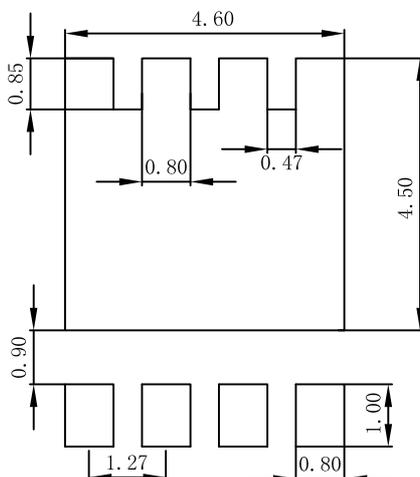
Bottom View



Side View

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
$\theta$	10°	12°	10°	12°

## PDFN 5x6 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.